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	Filing Date		2007-10-29
	First Named Inventor	Szeles	
	Art Unit	1752	
	Examiner Name	Not Yet Assigned	
Attorney Docket Number		4375-062621	

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	9	KUHN et al., Evidence of deep donor in CdTe, Journal of Crystal Growth, 1992, pages 660-665, Volume 117, Elsevier Science Publishers B.V.	<input type="checkbox"/>

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10	SETO et al., Chlorine-related photoluminescence lines in high-resistivity Cl-doped CdTe, Journal of Crystal Growth, pages 271-275, Volume 117, Elsevier Science Publishers B.V.	<input type="checkbox"/>
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